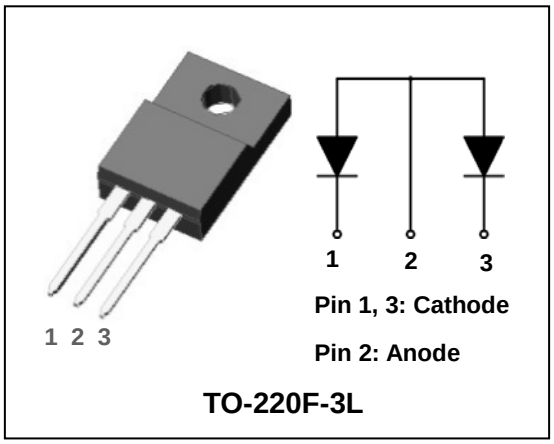
200V, 20A ULTRAFAST DUAL RECTIFIERS

Features

- Low forward voltage drop and leakage current
- Ultrafast reverse recovery time (trr<30ns)
- Low power loss and high efficiency
- Dual common anode rectifier construction
- Full lead (Pb)-free and RoHS compliant device



TO-220F-3L

Applications

- Switching power supply
- Power inverters
- Free-wheeling diode
- Power conversion system
- Motor drives

Product Characteristics

$I_{F(AV)}$	2 X 10A
V_{RRM}	200V
V_{FM} at 125℃	1.25V
t_{rr}	30ns

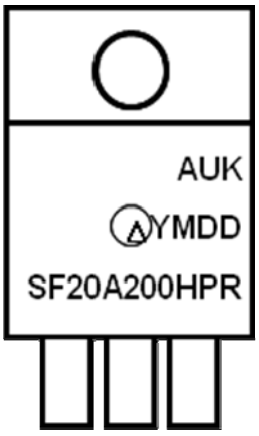
Description

The SF20A200HPR is an ultrafast rectifier. It has a low forward voltage drop and reverse recovery time (trr<30ns). The device is intended for use as a free wheeling, clamping rectifier in a variety of switching power supplies and other power switching applications.

Ordering Information

Device	Marking Code	Package	Packaging
SF20A200HPR	SF20A200HPR	TO-220F-3L	Tube

Marking Information



AUK = Manufacture Logo

Δ = Control Code of Manufacture

YMDD = Date Code Marking

-. Y = Year Code

-. M = Monthly Code

-. DD = Daily Code

SF20A200HPR = Specific Device Code

Absolute Maximum Ratings (Limiting Values)

Characteristic		Symbol	Value	Unit
Maximum repetitive reverse voltage Maximum working peak reverse voltage Maximum DC blocking voltage		V_{RRM} V_{RWM} V_R	200	V
Maximum average forward rectified current	per diode	$I_{F(AV)}$	10	A
	total device		20	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode		I_{FSM}	120	A
Storage temperature range		T_{stg}	-45℃ to +150℃	℃
Maximum operating junction temperature		T_j	150	℃

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Maximum thermal resistance junction to case	per diode	$R_{th(j-c)}$	4.0	℃/W
	total device		3.6	

Electrical Characteristics (Per Diode)

Characteristic	Symbol	Test Condition		Min.	Typ.	Max.	Unit
Peak forward voltage drop	V_{FM} (1)	I_{FM} = 10A	T_j=25℃	-	-	0.98	V
			T_j=125℃	-	-	0.88	V
Reverse leakage current	I_{RM} (1)	$V_R = V_{RRM}$	T_j=25℃	-	-	25	uA
			T_j=125℃	-	-	500	uA
Reverse recovery time	t_{rr}	I_F = 1A, di/dt =-100 A/us		-	-	30	ns
Junction capacitance	C_j	$V_R = 4V_{DC}$, f=1MHz		-	150	-	pF

Note : (1) Pulse test : $t_P \leq 380\ \mu s$, Duty cycle $\leq 2\%$

Rating and Characteristic Curves (Per Diode)

Fig. 1 V_F - I_F

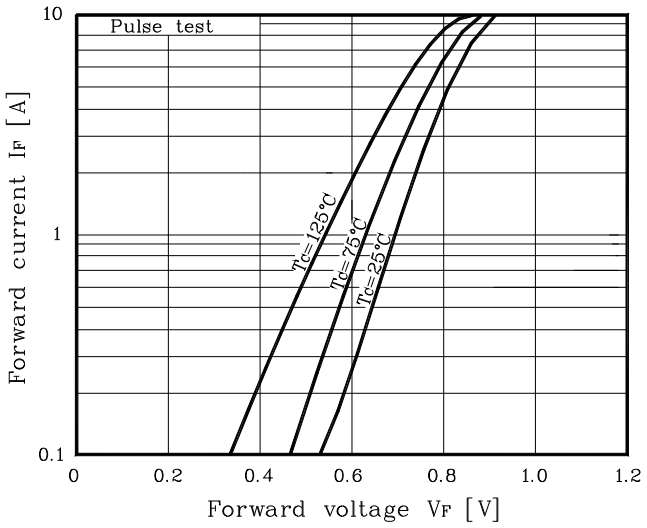


Fig. 2 I_R - V_R

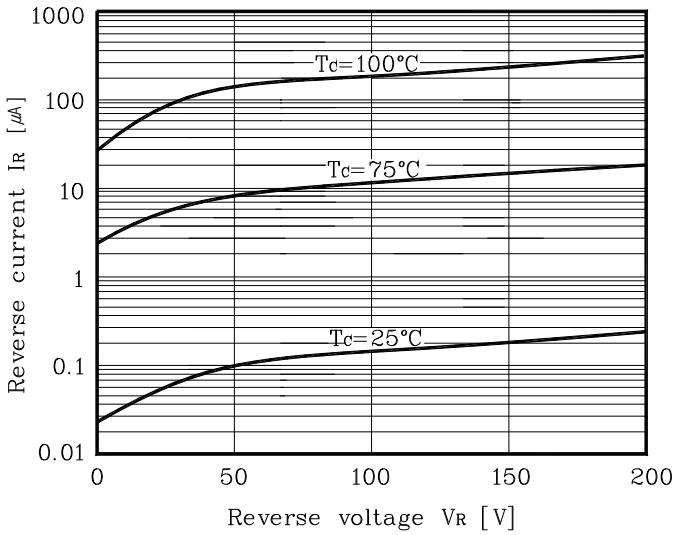


Fig. 3 I_O – P_F

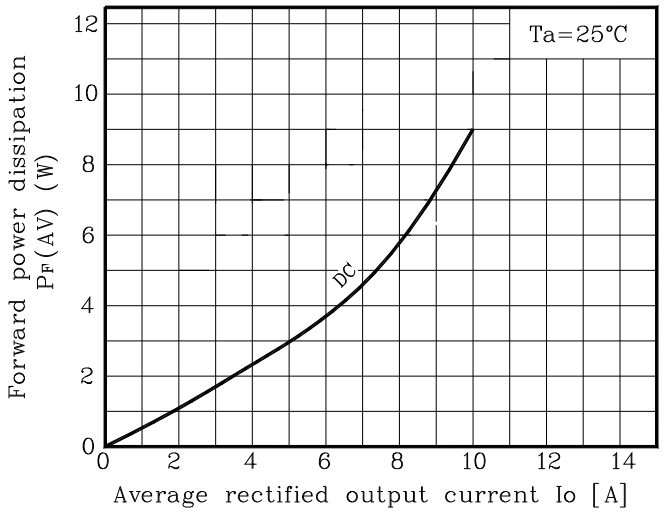


Fig. 4 C_T - V_R

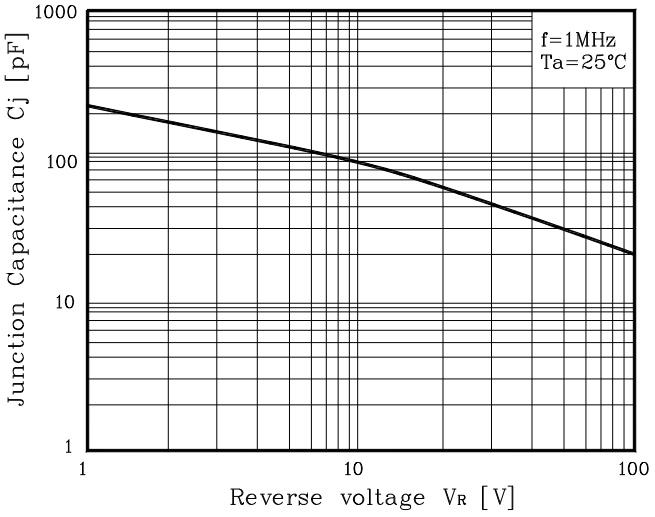


Fig. 5 I_{FSM} – Number of cycle

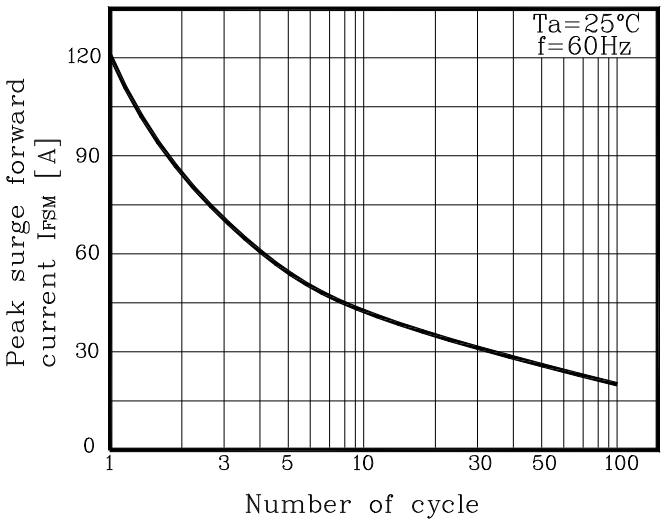
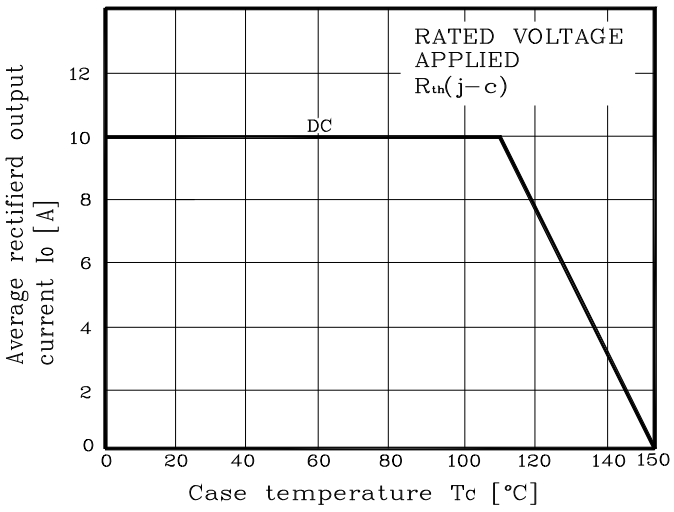
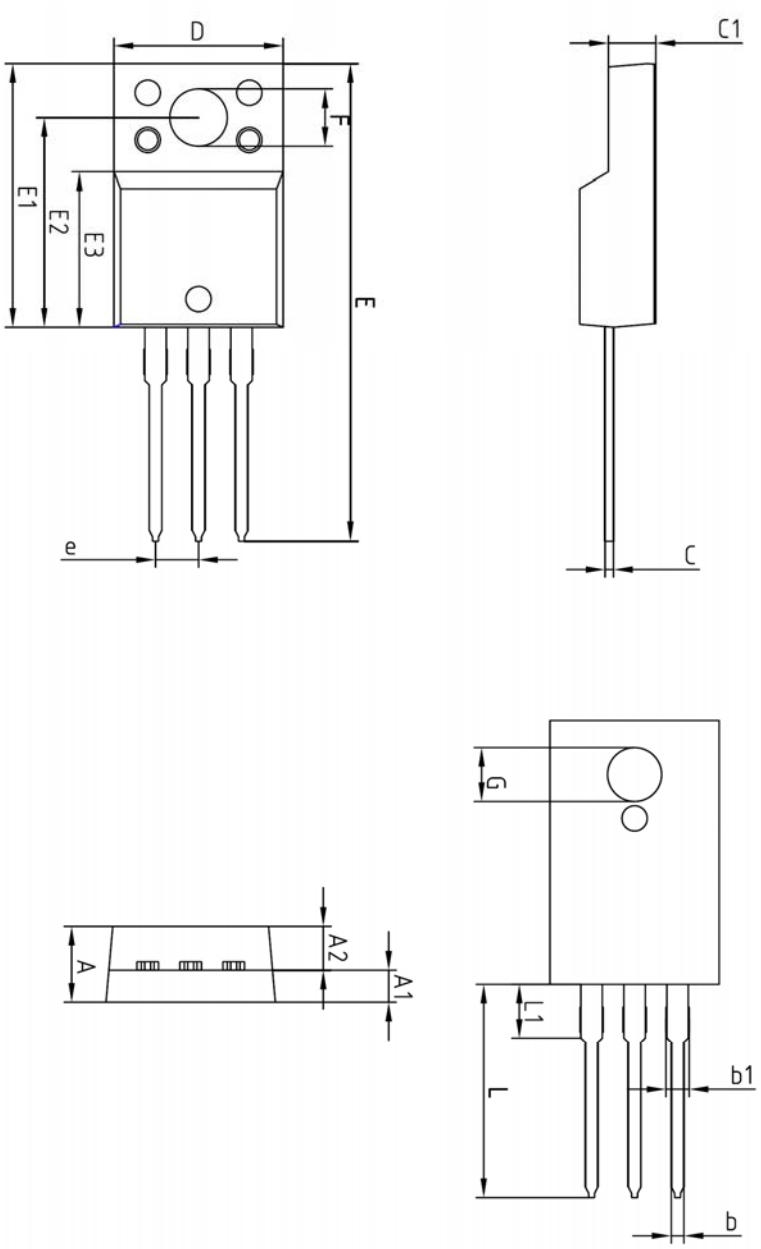


Fig. 6 I_O derating - T_C



Package Outline Dimension



SYMBOL	MILLIMETERS			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	–	–	4.60	
A1	2.45	2.50	2.55	
A2	1.95	2.00	2.05	
b	0.65	0.75	0.85	
b1	1.07	1.27	1.47	
C	0.40	0.50	0.60	
C1	2.70	2.80	2.90	
D	9.90	10.00	10.10	
E	28.00	–	28.60	
E1	15.50	15.60	15.70	
E2	12.30	12.40	12.50	
E3	9.15	9.20	9.25	
F	3.30	3.40	3.50	
G	3.10	3.20	3.30	
e	2.54 BSC			
L	12.40	–	13.00	
L1	3.46 BSC			

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